Demonstration Note for NCP1570

The NCP1570 demonstration board is a 3.6" by 1.8",

two-layer printed circuit board, optimized for small solution

size and lowest solution cost. This demonstration circuit can

be used to evaluate the performance and functionality of

NCP1570, Low Voltage Synchronous Buck Controller.

From a 5.0 V input with a 12 V bias supply, this board

produces a 2.5 V, 10 A output. The NCP1570 controller uses the $V^{2_{TM}}$ control scheme to achieve the fastest possible

transient response and best overall regulation, while using

the least number of external components. Another feature of

the NCP1570 is a Power Good output to indicate whether the

output signal is within regulation limits. The NCP1570 also

provides under-voltage lockout, soft start, and built-in

5.0 V/12 V Bias to 2.5 V/10 A Synchronous Buck Converter

Description

adaptive FET non-overlap.



ON Semiconductor[™]

http://onsemi.com

DEMONSTRATION NOTE

Features

- Synchronous Buck Topology
- 1% Output Voltage Regulation
- Entire 5.0 V to 2.5 V, 10 A Converter Fits in Less Than 2.3 in.²
- Power Good Output with Programmable Delay
- V² Control Method
- Fixed-Frequency Internal 200 kHz Oscillator
- 200 ns Transient Response
- 0 or 100% Duty Cycle During Load Transient
- Programmable Soft Start
- Under-Voltage Lockout
- Excellent Line and Load Regulation
- Low Output Voltage Ripple



Figure 1. NCP1570 Demonstration Board

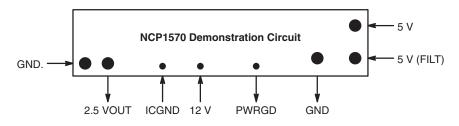


Figure 2. Application Diagram

TERMINAL DESCRIPTION

Terminal Name	Description	
5 V	Power stage power supply, 5.0 V recommended.	
5 V (FILT)	Power stage power supply, filtered with optional inductor, 5.0 V recommended.	
GND	Return for the 5.0 V supply.	
2.5 VOUT	2.5 V/10 A output.	
GND.	Return for the 2.5 V/10 A output.	
PWRGD	Power Good signal indicates output voltage in regulation.	
12 VIN	IC and MOSFET bias power supply, 12 V recommended.	
ICGND	Return for the 12 V supply.	

MAXIMUM RATINGS

Pin Name	V _{MAX}	V _{MIN}	ISOURCE	I _{SINK}
5 V	6.3 V	–0.3 V	N/A	10 A
5 V (FILT)	6.3 V	–0.3 V	N/A	10 A
GND	0.3 V	–0.3 V	15 A	N/A
2.5 VOUT	6.3 V	–0.3 V	17 A	N/A
GND.	0.3 V	–0.3 V	N/A	17 A
PWRGD	6.3 V	–0.3 V	1.0 mA	20 mA
12 VIN	15 V	–0.3 V	N/A	450 mADC
ICGND	0.3 V	–0.3 V	450 mADC	N/A

$\textbf{ELECTRICAL CHARACTERISTICS} \hspace{0.2in} (25^{\circ}C \leq T_{A} \leq 50^{\circ}C, \hspace{0.1in} 11 \hspace{0.1in} V \leq V_{IN} \leq 13.4 \hspace{0.1in} V, \hspace{0.1in} f_{SW} = 200 \hspace{0.1in} kHz, \hspace{0.1in} unless \hspace{0.1in} otherwise \hspace{0.1in} noted) \hspace{0.1in} (25^{\circ}C \leq T_{A} \leq 50^{\circ}C, \hspace{0.1in} 11 \hspace{0.1in} V \leq V_{IN} \leq 13.4 \hspace{0.1in} V, \hspace{0.1in} f_{SW} = 200 \hspace{0.1in} kHz, \hspace{0.1in} unless \hspace{0.1in} otherwise \hspace{0.1in} noted) \hspace{0.1in} (25^{\circ}C \leq T_{A} \leq 50^{\circ}C, \hspace{0.1in} 11 \hspace{0.1in} V \leq V_{IN} \leq 13.4 \hspace{0.1in} V, \hspace{0.1in} f_{SW} = 200 \hspace{0.1in} kHz, \hspace{0.1in} unless \hspace{0.1in} otherwise \hspace{0.1in} noted) \hspace{0.1in} (25^{\circ}C \leq T_{A} \leq 50^{\circ}C, \hspace{0.1in} 11 \hspace{0.1in} V \leq V_{IN} \leq 13.4 \hspace{0.1in} V, \hspace{0.1in} f_{SW} = 200 \hspace{0.1in} kHz, \hspace{0.1in} unless \hspace{0.1in} otherwise \hspace{0.1in} noted) \hspace{0.1in} (25^{\circ}C \leq T_{A} \leq 50^{\circ}C, \hspace{0.1in} 11 \hspace{0.1in} V \leq V_{IN} \leq 13.4 \hspace{0.1in} V, \hspace{0.1in} f_{SW} = 200 \hspace{0.1in} kHz, \hspace{0.1in} unless \hspace{0.1in} otherwise \hspace{0.1in} noted) \hspace{0.1in} (25^{\circ}C \leq T_{A} \leq 50^{\circ}C, \hspace{0.1in} 11 \hspace{0.1in} V \leq V_{IN} \leq 13.4 \hspace{0.1in} V, \hspace{0.1in} f_{SW} = 200 \hspace{0.1in} kHz, \hspace{0.1in} unless \hspace{0.1in} otherwise \hspace{0.1in} noted) \hspace{0.1in} (25^{\circ}C \leq T_{A} \leq 50^{\circ}C, \hspace{0.1in} 11 \hspace{0.1in} V \leq V_{IN} \leq 13.4 \hspace{0.1in} V, \hspace{0.1in} f_{SW} = 200 \hspace{0.1in} kHz, \hspace{0.1in} unless \hspace{0.1in} otherwise \hspace{0.1in} noted) \hspace{0.1in} (25^{\circ}C \leq T_{A} \leq 50^{\circ}C, \hspace{0.1in} 11 \hspace{0.1in} V \leq V_{IN} \leq 10.4 \hspace{0.1in} V, \hspace{0.1in} f_{SW} = 200 \hspace{0.1in} kHz, \hspace{0.1in} unless \hspace{0.1in} otherwise \hspace{0.1in} noted) \hspace{0.1in} (25^{\circ}C \leq T_{A} \leq 20^{\circ}C, \hspace{0.1in} (25^{\circ}C \leq 20^{\circ}C, \hspace{0.1in} (25^{\circ}C, \hspace{0.1in} (2$

Parameter	Test Conditions	Min	Тур	Max	Unit	
V _{OUT}						
Output Voltage	put Voltage 0.5 A < I(2.5 V _{OUT}) < 10 A		2.50	-	V	
Line Regulation	$10 \text{ V} \le \text{V}_{\text{IN}} (12 \text{ V}) \le 15 \text{ V}$	-	0.03	-	%	
Line Regulation	$4.5 \text{ V} \le \text{V}_{IN} (5.0 \text{ V}) \le 5.5 \text{ V}$	-	0.05	-	%	
Load Regulation	0.5 A < I(2.5 V _{OUT}) < 10 A	-	0.2	-	%	
Ripple and Noise	ople and Noise 0.5 A < I(2.5 V _{OUT}) < 10 A, 20 MHz Scope Bandwidth		25	-	mV _{PP}	
Transient Regulation	sient Regulation 5.0 A, 10 A/µs Load Step, 20 MHz Scope Bandwidth		92	-	mV	
Transient Recovery Time	5.0 A Load Step, 20 MHz Scope Bandwidth. Measure the time when output exceeds DC limit.		250	-	μs	
Efficiency	l(2.5 V _{OUT}) = 10 A		85	_	%	
V _{IN}						
Start Threshold	Start Threshold –		8.5	9.0	V	
Stop Threshold	o Threshold –		7.5	8.0	V	
General						
Switching Frequency	Switching Frequency Free Running		175	250	kHz	

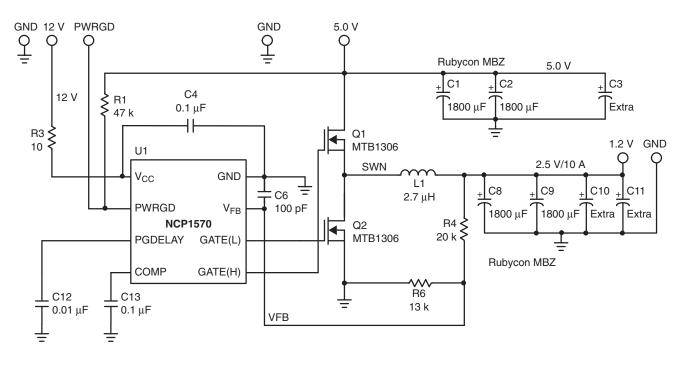
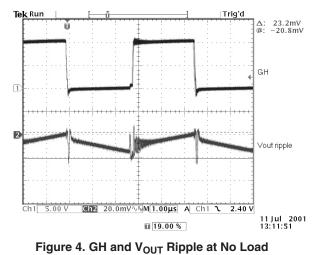


Figure 3. Demonstration Circuit Schematic

OPERATION GUIDELINES

- Two supplies are required to operate this converter. A 5.0 V supply capable of delivering at least 6.0 A is used to derive the output voltage. A 12 V supply capable of 50 mA is used to power the IC. Separate grounds are provided for each input.
- Connect a load directly to the 2.5 V output and its separate return ground. A short connection to the load will ensure the best load regulation and smallest output ripple voltage.
- The Power Good output is high when the output is within 90% of regulation. When the output falls below 70% of design output voltage, Power Good goes low. The Power Good pin is pulled high through a 47 k Ω resistor to the 5.0 V line.
- The IC reference voltage is 0.985 V. A 13 k/20 k resistor divider is used to set the output voltage to 2.5 V. These components can be changed to provide any desired voltage between 0.985 V and 5 V, however, some small jitter may become noticeable below 1.2 V output. Also, the series combination of the two resistors should be large enough (at least 10 k) to avoid pulling too much current.
- If the user requires a lower input current slew rate or less voltage drop at the 5.0 V input, provisions have been made to add an inductor. If an input inductor is used, additional input capacitance will be necessary to prevent damage to the existing input capacitors.



TYPICAL PERFORMANCE CHARACTERISTICS

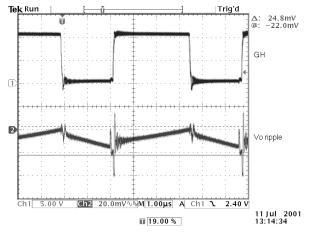


Figure 5. GH and V_{OUT} Ripple at 10 A Load

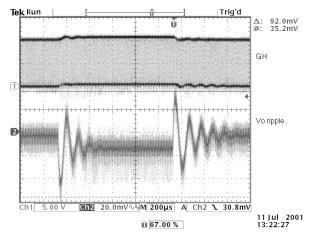


Figure 6. GH and V_{OUT} Ripple in 50 mA–10 A Transient Load



	V _{OUT}	V _{OUT}	
Load	0	10	А
Top FET	31	62	°C
Bottom FET	33	58	°C
Inductor	38	58	°C
Input Cap.	30	48	°C
Output Cap.	30	41	°C
IC	42	55	°C

BILL OF MATERIALS

Item	Qty	Reference	Part	Mfg. & P/N	Distributor
1	4	C1, 2, 8, 9	1800 μF	Rubycon MBZ–Series Low ESR Capacitor	Masline 716–546–5373
2	1	C3, 10, 11	Empty	Provision	-
3	2	C4, 13	Ceramic, 0.1 µF/25 V 0805	Panasonic ECJ-3VB1E104K	Digi–Key 800–344–4539
4	1	C6	Ceramic, 100 pF/25 V 0805	Panasonic TBD	Digi–Key 800–344–4539
5	1	C12	Ceramic, 0.01 µF/25 V 0805	Panasonic TBD	Digi–Key 800–344–4539
6	1	L1	2.7 μH Inductor 8T #16AWG on a T50–52B Micrometals Core	_	_
7	2	Q1, Q2	N–Channel D ² PAK MOSFET 30 V/30 A	ON Semiconductor MTB1306	ON Semiconductor 800–282–9855
8	1	R1	Resistor 47 kΩ 5% 0805	Panasonic TBD	Digi–Key 800–344–4539
9	1	R3	Resistor 10 kΩ 5% 0805	Panasonic TBD	Digi–Key 800–344–4539
10	1	R4	Resistor 20 kΩ 1% 0805	Panasonic TBD	Digi–Key 800–344–4539
11	1	R6	Resistor 13 kΩ 1% 0805	Panasonic TBD	Digi–Key 800–344–4539
12	1	U1	Low–Voltage Synchronous Buck Controller	ON Semiconductor NCP1570	ON Semiconductor 800–282–9855

PCB LAYOUT

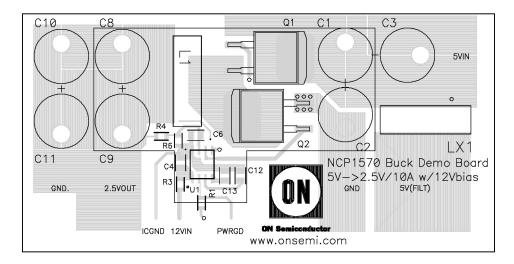


Figure 7. Top Layer and Top Silk

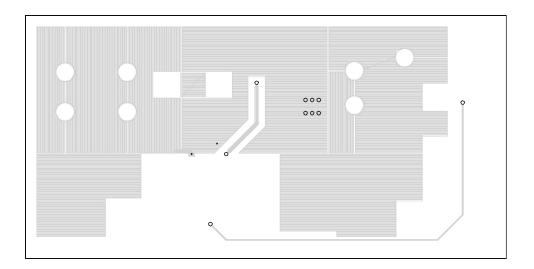


Figure 8. Bottom Layer

<u>Notes</u>

V² is a trademark of Switch Power, Inc.

ON Semiconductor and **W** are trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer.

PUBLICATION ORDERING INFORMATION

Literature Fulfillment:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada Fax: 303–675–2176 or 800–344–3867 Toll Free USA/Canada Email: ONlit@hibbertco.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

JAPAN: ON Semiconductor, Japan Customer Focus Center 4–32–1 Nishi–Gotanda, Shinagawa–ku, Tokyo, Japan 141–0031 Phone: 81–3–5740–2700 Email: r14525@onsemi.com

ON Semiconductor Website: http://onsemi.com

For additional information, please contact your local Sales Representative.